

# **RKZ6.2Z4MFAKT**

Silicon Planar Zener Diode for Surge Absorption

REJ03G1349-0100 Rev.1.00 Feb 21, 2006

SIA

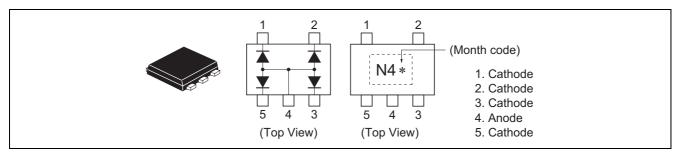
### Features

- RKZ6.2Z4MFA has four devices in a monolithic, and can absorb surge.
- Low capacitance (C = 4.0 pF Typ) and can protect ESD of signal line.
- VSON-5 Package is suitable for high density surface mounting.

### **Ordering Information**

Type No.	Laser Mark	Package Name	Package Code	
RKZ6.2Z4MFAKT	N4	VSON-5	PUSN0005KB-A	

### **Pin Arrangement**



### Month Code

Assemble			Assemble	
JAPAN	MALAYSIA	Month of Manufacture	JAPAN	MALAYS
А	1	July	G	7
В	2	August	Н	8
С	3	September	J	9
D	4	October	К	W
E	5	November	L	Х
F	6	December	М	Y
	<b>JAPAN</b> A	JAPANMALAYSIAA1B2C3D4E5	JAPANMALAYSIAMonth of ManufactureA1JulyB2AugustC3SeptemberD4OctoberE5November	JAPANMALAYSIAMonth of ManufactureJAPANA1JulyGB2AugustHC3SeptemberJD4OctoberKE5NovemberL



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

ltem	Symbol	Value	Unit
Power dissipation	Pd *	150	mW
Junction temperature	Тј	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note: Four device total, See Fig.2.

## Electrical Characteristics \*1

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Zener voltage	Vz	5.90	—	6.50	V	$I_Z = 5 \text{ mA}, 40 \text{ ms pulse}$
Reverse current	I <sub>R</sub>	—	—	3	μA	V <sub>R</sub> = 5.5 V
Capacitance	С	—	4.0	4.5	pF	$V_R = 0 V$ , f = 1 MHz
Dynamic resistance	r <sub>d</sub>	_	—	60	Ω	$I_Z = 5 \text{ mA}$
ESD-Capability *2, *3	—	8	—	_	kV	C = 150 pF, R = 330 $\Omega$ , Both forward and
						reverse direction 10 pulse

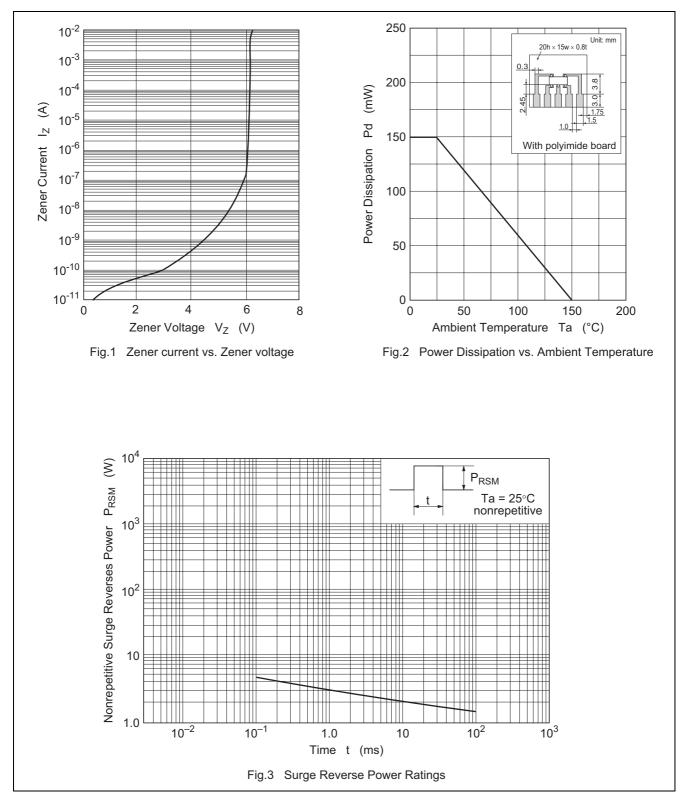
Notes: 1. Per one device.

2. Failure criterion ;  $I_R$  > 3  $\mu A$  at  $V_R$  = 5.5 V.

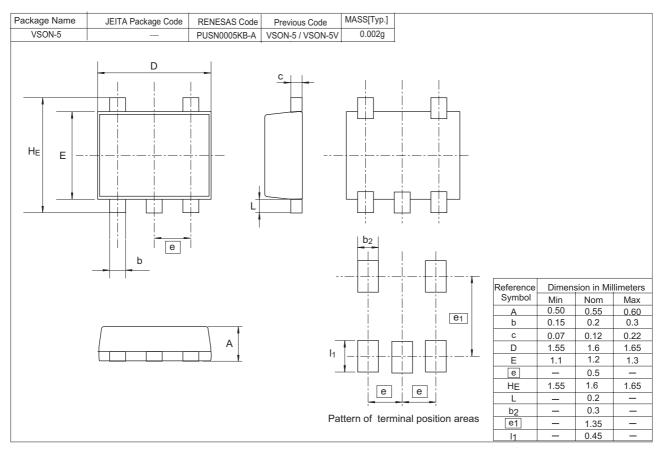
3. Between cathode and anode.



### **Main Characteristics**



### **Package Dimensions**





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